

MITSUBISHI THYRISTOR MODULES

TM200DZ/CZ/PZ-M,-H,-24,-2H

HIGH POWER GENERAL USE
INSULATED TYPE

TM200DZ/CZ/PZ-M,-H,-24,-2H



(DZ Type)

- **IT (AV)** Average on-state current **200A**
- **VRRM** Repetitive peak reverse voltage
..... **400/800/1200/1600V**
- **VDRM** Repetitive peak off-state voltage
..... **400/800/1200/1600V**
- **DOUBLE ARMS**
- **Insulated Type**
- **UL Recognized**

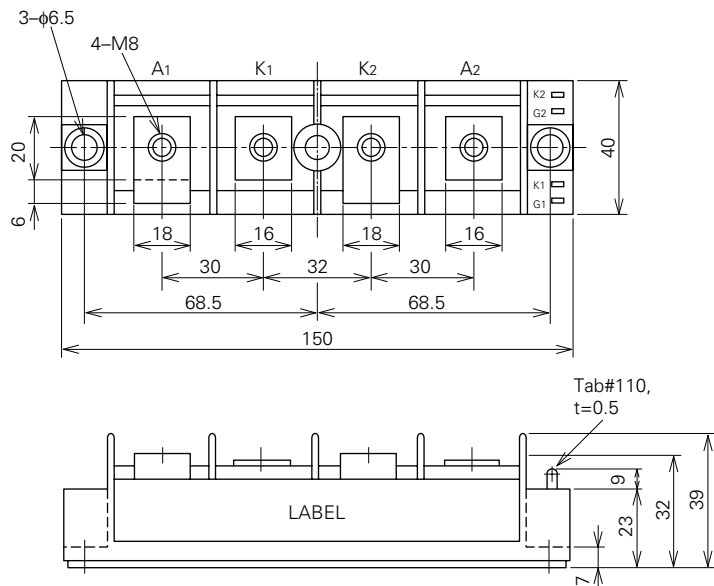
Yellow Card No. E80276 (N)
File No. E80271

APPLICATION

DC motor control, NC equipment, AC motor control, Contactless switches,
Electric furnace temperature control, Light dimmers

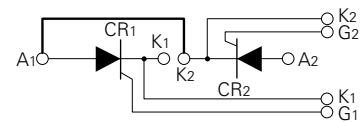
OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm

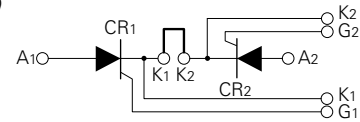


(DZ Type)

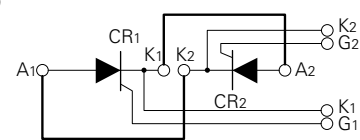
(DZ)



(CZ)



(PZ)



(Bold line is connective bar.)

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Voltage class				Unit
		M	H	24	2H	
VRRM	Repetitive peak reverse voltage	400	800	1200	1600	V
VRSM	Non-repetitive peak reverse voltage	480	960	1350	1700	V
VR (DC)	DC reverse voltage	320	640	960	1280	V
VDRM	Repetitive peak off-state voltage	400	800	1200	1600	V
VDSM	Non-repetitive peak off-state voltage	480	960	1350	1700	V
VD (DC)	DC off-state voltage	320	640	960	1280	V

Symbol	Parameter	Conditions	Ratings	Unit
IT (RMS)	RMS on-state current		310	A
IT (AV)	Average on-state current	Single-phase, half-wave 180° conduction, Tc=64°C	200	A
ITSM	Surge (non-repetitive) on-state current	One half cycle at 60Hz, peak value	4000	A
I ² t	I ² t for fusing	Value for one cycle of surge current	6.7 × 10 ⁴	A ² s
di/dt	Critical rate of rise of on-state current	VD=1/2VDRM, IG=1.0A, Tj=125°C	100	A/μs
PGM	Peak gate power dissipation		10	W
PG (AV)	Average gate power dissipation		3.0	W
VFGM	Peak gate forward voltage		10	V
VRGM	Peak gate reverse voltage		5.0	V
IFGM	Peak gate forward current		4.0	A
Tj	Junction temperature		-40~+125	°C
Tstg	Storage temperature		-40~+125	°C
Viso	Isolation voltage	Charged part to case	2500	V
—	Mounting torque	Main terminal screw M8	8.83~10.8	N·m
			90~110	kg·cm
		Mounting screw M6	1.96~3.92	N·m
—	Weight	Typical value	20~40	kg·cm
			300	g

ELECTRICAL CHARACTERISTICS

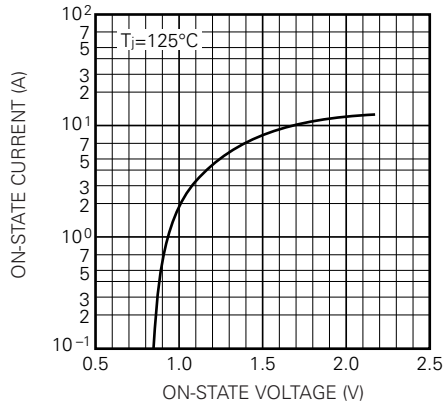
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive peak reverse current	Tj=125°C, VRRM applied	—	—	30	mA
IDRM	Repetitive peak off-state current	Tj=125°C, VDRM applied	—	—	30	mA
VTM	On-state voltage	Tj=125°C, ITM=600A, instantaneous meas.	—	—	1.35	V
dv/dt	Critical rate of rise of off-state voltage	Tj=125°C, VD=2/3VDRM	500	—	—	V/μs
VGT	Gate trigger voltage	Tj=25°C, VD=6V, RL=2Ω	—	—	3.0	V
VGD	Gate non-trigger voltage	Tj=125°C, VD=1/2VDRM	0.25	—	—	V
IGT	Gate trigger current	Tj=25°C, VD=6V, RL=2Ω	15	—	100	mA
Rth (j-c)	Thermal resistance	Junction to case (per 1/2 module)	—	—	0.2	°C/W
Rth (c-f)	Contact thermal resistance	Case to fin, conductive grease applied (per 1/2 module)	—	—	0.1	°C/W
—	Insulation resistance	Measured with a 500V megohmmeter between main terminal and case	10	—	—	MΩ

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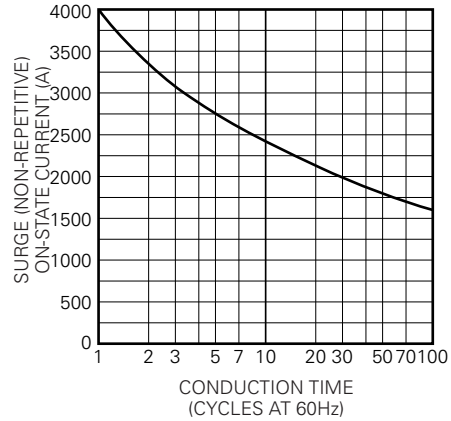
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PERFORMANCE CURVES

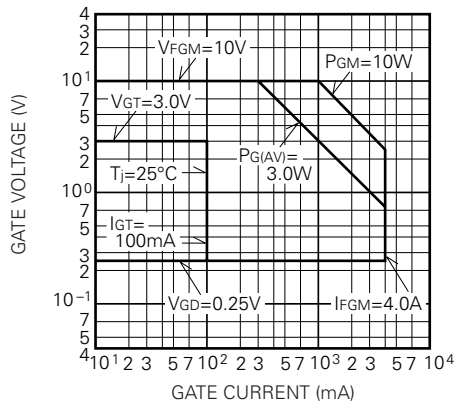
MAXIMUM ON-STATE CHARACTERISTIC



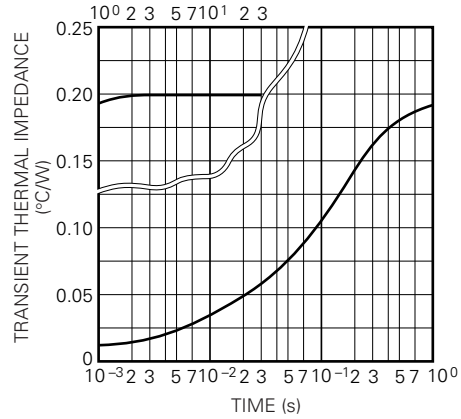
RATED SURGE (NON-REPETITIVE) ON-STATE CURRENT



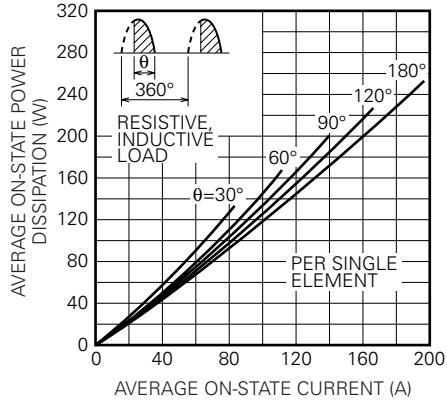
GATE CHARACTERISTICS



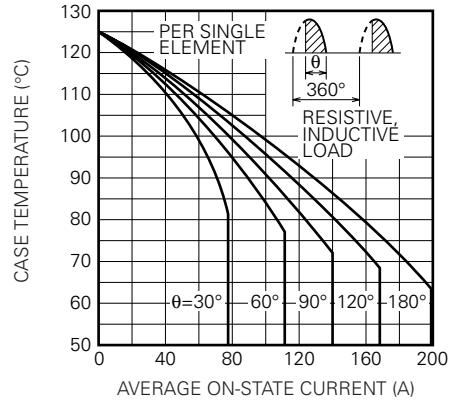
MAXIMUM TRANSIENT THERMAL IMPEDANCE (JUNCTION TO CASE)



MAXIMUM AVERAGE ON-STATE POWER DISSIPATION (SINGLE PHASE HALFWAVE)



LIMITING VALUE OF THE AVERAGE ON-STATE CURRENT (SINGLE PHASE HALFWAVE)



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